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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

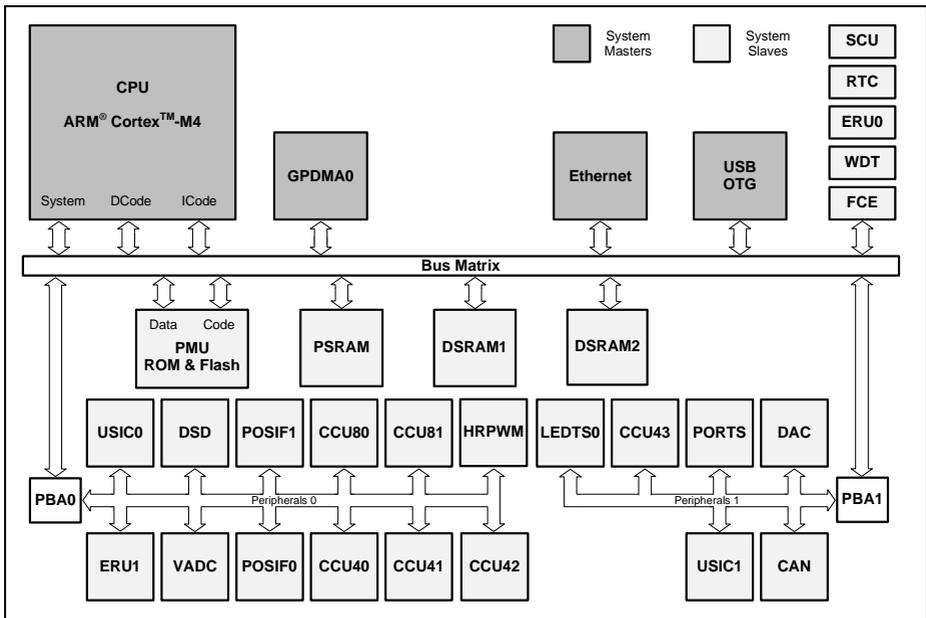
Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	CANbus, Ethernet, I <sup>2</sup> C, LINbus, SPI, UART, USB
Peripherals	DMA, I <sup>2</sup> S, LED, POR, PWM, WDT
Number of I/O	55
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	80K x 8
Voltage - Supply (Vcc/Vdd)	3.13V ~ 3.63V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP Exposed Pad
Supplier Device Package	PG-LQFP-100-25
Purchase URL	<a href="https://www.e-xfl.com/product-detail/infineon-technologies/xmc4400f100k512abxuma1">https://www.e-xfl.com/product-detail/infineon-technologies/xmc4400f100k512abxuma1</a>

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## 1 Summary of Features

The XMC4400 devices are members of the XMC4000 Family of microcontrollers based on the ARM Cortex-M4 processor core. The XMC4000 is a family of high performance and energy efficient microcontrollers optimized for Industrial Connectivity, Industrial Control, Power Conversion, Sense & Control.



**Figure 1 System Block Diagram**

### CPU Subsystem

- CPU Core
  - High Performance 32-bit ARM Cortex-M4 CPU
  - 16-bit and 32-bit Thumb2 instruction set
  - DSP/MAC instructions
  - System timer (SysTick) for Operating System support
- Floating Point Unit
- Memory Protection Unit
- Nested Vectored Interrupt Controller
- One General Purpose DMA with up-to 8 channels
- Event Request Unit (ERU) for programmable processing of external and internal service requests
- Flexible CRC Engine (FCE) for multiple bit error detection

**On-Chip Memories**

- 16 KB on-chip boot ROM
- 16 KB on-chip high-speed program memory
- 32 KB on-chip high speed data memory
- 32 KB on-chip high-speed communication memory
- 512 KB on-chip Flash Memory with 4 KB instruction cache

**Communication Peripherals**

- Ethernet MAC module capable of 10/100 Mbit/s transfer rates
- Universal Serial Bus, USB 2.0 host, Full-Speed OTG, with integrated PHY
- Controller Area Network interface (MultiCAN), Full-CAN/Basic-CAN with two nodes, 64 message objects (MO), data rate up to 1MBit/s
- Four Universal Serial Interface Channels (USIC), providing four serial channels, usable as UART, double-SPI, quad-SPI, IIC, IIS and LIN interfaces
- LED and Touch-Sense Controller (LEDTS) for Human-Machine interface

**Analog Frontend Peripherals**

- Four Analog-Digital Converters (VADC) of 12-bit resolution, 8 channels each, with input out-of-range comparators
- Delta Sigma Demodulator with four channels, digital input stage for A/D signal conversion
- Digital-Analog Converter (DAC) with two channels of 12-bit resolution

**Industrial Control Peripherals**

- Two Capture/Compare Units 8 (CCU8) for motor control and power conversion
- Four Capture/Compare Units 4 (CCU4) for use as general purpose timers
- Four High Resolution PWM (HRPWM) channels
- Two Position Interfaces (POSIF) for servo motor positioning
- Window Watchdog Timer (WDT) for safety sensitive applications
- Die Temperature Sensor (DTS)
- Real Time Clock module with alarm support
- System Control Unit (SCU) for system configuration and control

**Input/Output Lines**

- Programmable port driver control module (PORTS)
- Individual bit addressability
- Tri-stated in input mode
- Push/pull or open drain output mode
- Boundary scan test support over JTAG interface

**Table 7 ADC Channels<sup>1)</sup>**

Package	VADC G0	VADC G1	VADC G2	VADC G3
PG-LQFP-100	CH0..CH7	CH0..CH7	CH0..CH3	CH0..CH3
PG-LQFP-64	CH0, CH3..CH7	CH0, CH1, CH3, CH6	CH0, CH1	CH2, CH3

1) Some pins in a package may be connected to more than one channel. For the detailed mapping see the Port I/O Function table.

## 1.6 Identification Registers

The identification registers allow software to identify the marking.

**Table 8 XMC4400 Identification Registers**

Register Name	Value	Marking
SCU_IDCHIP	0004 4001 <sub>H</sub>	EES-AA, ES-AA
SCU_IDCHIP	0004 4002 <sub>H</sub>	ES-AB, AB
SCU_IDCHIP	0004 4003 <sub>H</sub>	BA
JTAG IDCODE	101D C083 <sub>H</sub>	EES-AA, ES-AA
JTAG IDCODE	201D C083 <sub>H</sub>	ES-AB, AB
JTAG IDCODE	301D C083 <sub>H</sub>	BA

**General Device Information**

**Table 10 Package Pin Mapping (cont'd)**

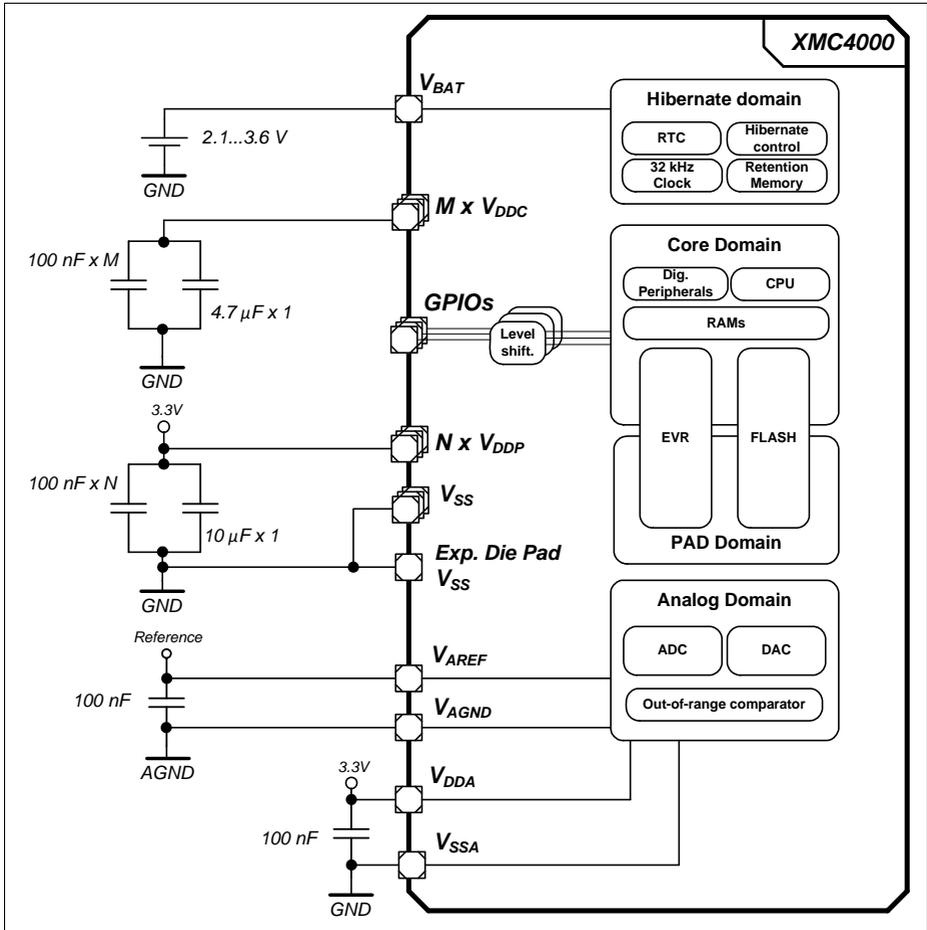
Function	LQFP-100	LQFP-64 TQFP-64	Pad Type	Notes
P3.0	7	-	A2	
P3.1	6	-	A2	
P3.2	5	-	A2	
P3.3	93	-	A1+	
P3.4	92	-	A1+	
P3.5	91	-	A2	
P3.6	90	-	A2	
P4.0	85	-	A2	
P4.1	84	-	A2	
P5.0	58	-	A1+	
P5.1	57	-	A1+	
P5.2	56	-	A1+	
P5.7	55	-	A1+	
P14.0	31	20	AN/DIG_IN	
P14.1	30	-	AN/DIG_IN	
P14.2	29	-	AN/DIG_IN	
P14.3	28	19	AN/DIG_IN	
P14.4	27	18	AN/DIG_IN	
P14.5	26	17	AN/DIG_IN	
P14.6	25	16	AN/DIG_IN	
P14.7	24	15	AN/DIG_IN	
P14.8	37	24	AN/DAC/DIG_I N	
P14.9	36	23	AN/DAC/DIG_I N	
P14.12	23	-	AN/DIG_IN	
P14.13	22	-	AN/DIG_IN	
P14.14	21	14	AN/DIG_IN	
P14.15	20	-	AN/DIG_IN	
P15.2	19	-	AN/DIG_IN	
P15.3	18	-	AN/DIG_IN	
P15.8	39	-	AN/DIG_IN	
P15.9	38	-	AN/DIG_IN	

**Table 12 Port I/O Functions (cont'd)**

Function	Output					Input								
	ALT1	ALT2	ALT3	ALT4	HWO0	HWI0	Input	Input	Input	Input	Input	Input	Input	Input
P1.7		U0C0. DOU0	DSD. MCLK2	U1C1. SELO2				DSD. MCLK2A			DSD. MCLK0C			
P1.8		U0C0. SELO1	DSD. MCLK1	U1C1. SCLKOUT				DSD. MCLK1A			DSD. MCLK0D	DSD. MCLK2D	DSD. MCLK3D	
P1.9	U0C0. SCLKOUT		DSD. MCLK0	U1C1. DOU0				DSD. MCLK0A			DSD. MCLK1C	DSD. MCLK2C	DSD. MCLK3C	
P1.10	ETH0. MDC	U0C0. SCLKOUT	CCU81. OUT21								CCU41. IN2C			
P1.11		U0C0. SELO0	CCU81. OUT11		ETH0. MDO	ETH0. MDIC					CCU41. IN3C			
P1.12	ETH0. TX_EN	CAN. N1_TXD	CCU81. OUT01											
P1.13	ETH0. TXD0	U0C1. SELO3	CCU81. OUT20					CAN. N1_RXDC						
P1.14	ETH0. TXD1	U0C1. SELO2	CCU81. OUT10											
P1.15	SCU. EXTCLK	DSD. MCLK2	CCU81. OUT00	U1C0. DOU0	DB. ETM_TRACED ATA3			DSD. MCLK2B			ERU1. 1A0			
P2.0	CAN. N0_TXD	CCU81. OUT21	DSD. CGPWMN	LEDTS0. COL1	ETH0. MDO	ETH0. MDIB				ERU0. 0B3		CCU40. IN1C		
P2.1		CCU81. OUT11	DSD. CGPWMN	LEDTS0. COL0	DB.TDQ/ TRACESWO			ETH0. CLK_RMIIA			ERU1. 0B0	CCU40. IN0C		ETH0. CLKRXA
P2.2	VADC. EMUX00	CCU81. OUT01	CCU41. OUT3	LEDTS0. LINE0	LEDTS0. EXTENDED0	LEDTS0. TSIN0A	ETH0. RXD0A	U0C1. DX0A	ERU0. 1B2		CCU41. IN3A			
P2.3	VADC. EMUX01	U0C1. SELO0	CCU41. OUT2	LEDTS0. LINE1	LEDTS0. EXTENDED1	LEDTS0. TSIN1A	ETH0. RXD1A	U0C1. DX2A	ERU0. 1A2	POSIF1. IN2A	CCU41. IN2A			
P2.4	VADC. EMUX02	U0C1. SCLKOUT	CCU41. OUT1	LEDTS0. LINE2	LEDTS0. EXTENDED2	LEDTS0. TSIN2A	ETH0. RXERA	U0C1. DX1A	ERU0. 0B2	POSIF1. IN1A	CCU41. IN1A	HRPWM0. BL1A		
P2.5	ETH0. TX_EN	U0C1. DOU0	CCU41. OUT0	LEDTS0. LINE3	LEDTS0. EXTENDED3	LEDTS0. TSIN3A	ETH0. RXDVA	U0C1. DX0B	ERU0. 0A2	POSIF1. IN0A	CCU41. IN0A	HRPWM0. BL2A		ETH0. CRS_DVA
P2.6			CCU80. OUT13	LEDTS0. COL3			DSD. DIN1B	CAN. N1_RXDA	ERU0. 1B3		CCU40. IN3C			
P2.7	ETH0. MDC	CAN. N1_TXD	CCU80. OUT03	LEDTS0. COL2			DSD. DIN0B			ERU1. 1B0	CCU40. IN2C			
P2.8	ETH0. TXD0		CCU80. OUT32	LEDTS0. LINE4	LEDTS0. EXTENDED4	LEDTS0. TSIN4A	DAC. TRIGGER5				CCU40. IN0B	CCU40. IN1B	CCU40. IN2B	CCU40. IN3B
P2.9	ETH0. TXD1		CCU80. OUT22	LEDTS0. LINE5	LEDTS0. EXTENDED5	LEDTS0. TSIN5A	DAC. TRIGGER4				CCU41. IN0B	CCU41. IN1B	CCU41. IN2B	CCU41. IN3B
P2.10	VADC. EMUX10													
P2.14	VADC. EMUX11	U1C0. DOU0	CCU80. OUT21		DB. ETM_TRACEC LK			U1C0. DX0D			CCU43. IN0B	CCU43. IN1B	CCU43. IN2B	CCU43. IN3B
P2.15	VADC. EMUX12		CCU80. OUT11	LEDTS0. LINE6	LEDTS0. EXTENDED6	LEDTS0. TSIN6A	ETH0. COLA	U1C0. DX0C			CCU42. IN0B	CCU42. IN1B	CCU42. IN2B	CCU42. IN3B

### 2.3 Power Connection Scheme

Figure 7. shows a reference power connection scheme for the XMC4400.



**Figure 7 Power Connection Scheme**

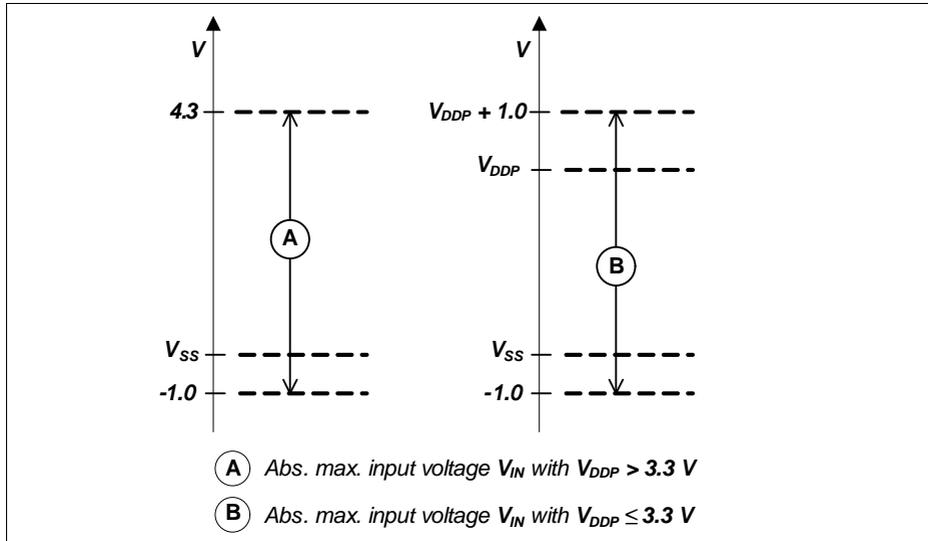
Every power supply pin needs to be connected. Different pins of the same supply need also to be externally connected. As example, all  $V_{DDP}$  pins must be connected externally to one  $V_{DDP}$  net. In this reference scheme one 100 nF capacitor is connected at each supply pin against  $V_{SS}$ . An additional 10  $\mu$ F capacitor is connected to the  $V_{DDP}$  nets and an additional 4.7 $\mu$ F capacitor to the  $V_{DDC}$  nets.

The XMC4400 has a common ground concept, all  $V_{SS}$ ,  $V_{SSA}$  and  $V_{SSO}$  pins share the same ground potential. In packages with an exposed die pad it must be connected to the common ground as well.

$V_{AGND}$  is the low potential to the analog reference  $V_{AREF}$ . Depending on the application it can share the common ground or have a different potential. In devices with shared  $V_{DDA}/V_{AREF}$  and  $V_{SSA}/V_{AGND}$  pins the reference is tied to the supply. Some analog channels can optionally serve as "Alternate Reference"; further details on this operating mode are described in the Reference Manual.

When  $V_{DDP}$  is supplied,  $V_{BAT}$  must be supplied as well. If no other supply source (e.g. battery) is connected to  $V_{BAT}$ , the  $V_{BAT}$  pin can also be connected directly to  $V_{DDP}$ .

**Figure 8** explains the input voltage ranges of  $V_{IN}$  and  $V_{AIN}$  and its dependency to the supply level of  $V_{DDP}$ . The input voltage must not exceed 4.3 V, and it must not be more than 1.0 V above  $V_{DDP}$ . For the range up to  $V_{DDP} + 1.0$  V also see the definition of the overload conditions in **Section 3.1.3**.



**Figure 8 Absolute Maximum Input Voltage Ranges**

### 3.1.3 Pin Reliability in Overload

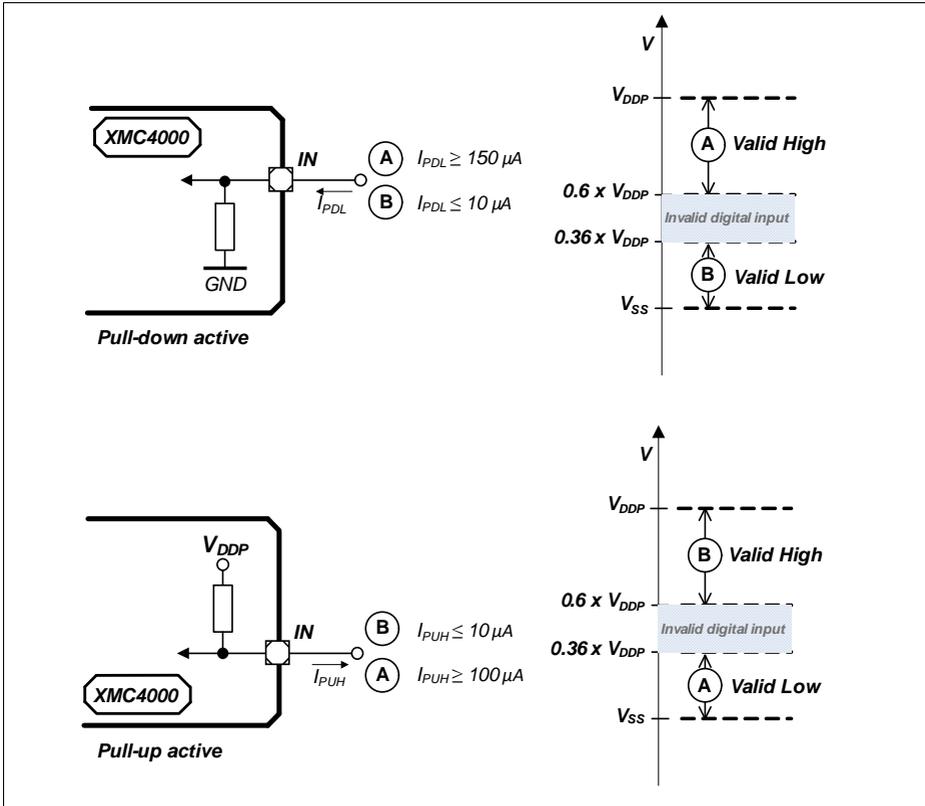
When receiving signals from higher voltage devices, low-voltage devices experience overload currents and voltages that go beyond their own IO power supplies specification.

**Table 14** defines overload conditions that will not cause any negative reliability impact if all the following conditions are met:

- full operation life-time is not exceeded
- **Operating Conditions** are met for
  - pad supply levels ( $V_{DDP}$  or  $V_{DDA}$ )
  - temperature

If a pin current is outside of the **Operating Conditions** but within the overload parameters, then the parameters functionality of this pin as stated in the Operating Conditions can no longer be guaranteed. Operation is still possible in most cases but with relaxed parameters.

*Note: An overload condition on one or more pins does not require a reset.*



**Figure 11 Pull Device Input Characteristics**

**Figure 11** visualizes the input characteristics with an active internal pull device:

- in the cases "A" the internal pull device is overridden by a strong external driver;
- in the cases "B" the internal pull device defines the input logical state against a weak external load.

**Table 24 HIB\_IO Class\_A1 special Pads**

Parameter	Symbol	Values		Unit	Note / Test Condition
		Min.	Max.		
Input leakage current	$I_{OZHIB}$ CC	-500	500	nA	$0\text{ V} \leq V_{IN} \leq V_{BAT}$
Input high voltage	$V_{IHIB}$ SR	$0.6 \times V_{BAT}$	$V_{BAT} + 0.3$	V	max. 3.6 V
Input low voltage	$V_{ILHIB}$ SR	-0.3	$0.36 \times V_{BAT}$	V	
Input Hysteresis for HIB_IO pins <sup>1)</sup>	$HYSHIB$ CC	$0.1 \times V_{BAT}$	–	V	$V_{BAT} \geq 3.13\text{ V}$
		$0.06 \times V_{BAT}$	–	V	$V_{BAT} < 3.13\text{ V}$
Output high voltage, POD <sup>1)</sup> = medium	$V_{OHIB}$ CC	$V_{BAT} - 0.4$	–	V	$I_{OH} \geq -1.4\text{ mA}$
Output low voltage	$V_{OLHIB}$ CC	–	0.4	V	$I_{OL} \leq 2\text{ mA}$
Fall time	$t_{FHIB}$ CC	–	50	ns	$V_{BAT} \geq 3.13\text{ V}$ $C_L = 50\text{ pF}$
		–	100	ns	$V_{BAT} < 3.13\text{ V}$ $C_L = 50\text{ pF}$
Rise time	$t_{RHIB}$ CC	–	50	ns	$V_{BAT} \geq 3.13\text{ V}$ $C_L = 50\text{ pF}$
		–	100	ns	$V_{BAT} < 3.13\text{ V}$ $C_L = 50\text{ pF}$

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can not be guaranteed that it suppresses switching due to external system noise.

**Electrical Parameters**
**Table 27 DAC Parameters (Operating Conditions apply) (cont'd)**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Offset error	$ED_{OFF}$ CC		±20		mV	
Gain error	$ED_{G\_IN}$ CC	-5	0	5	%	
Startup time	$t_{STARTUP}$ CC	–	15	30	µs	time from output enabling till code valid ±16 LSB
3dB Bandwidth of Output Buffer	$f_{C1}$ CC	2.5	5	–	MHz	verified by design
Output sourcing current	$I_{OUT\_SOURCE}$ CC	–	-30	–	mA	
Output sinking current	$I_{OUT\_SINK}$ CC	–	0.6	–	mA	
Output resistance	$R_{OUT}$ CC	–	50	–	Ohm	
Load resistance	$R_L$ SR	5	–	–	kOhm	
Load capacitance	$C_L$ SR	–	–	50	pF	
Signal-to-Noise Ratio	SNR CC	–	70	–	dB	examination bandwidth < 25 kHz
Total Harmonic Distortion	THD CC	–	70	–	dB	examination bandwidth < 25 kHz
Power Supply Rejection Ratio	PSRR CC	–	56	–	dB	to $V_{DDA}$ verified by design

1) According to best straight line method.

**Conversion Calculation**

Unsigned:

$$DACxDATA = 4095 \times (V_{OUT} - V_{OUT\_MIN}) / (V_{OUT\_MAX} - V_{OUT\_MIN})$$

Signed:

$$DACxDATA = 4095 \times (V_{OUT} - V_{OUT\_MIN}) / (V_{OUT\_MAX} - V_{OUT\_MIN}) - 2048$$

### 3.2.4 Out-of-Range Comparator (ORC)

The Out-of-Range Comparator (ORC) triggers on analog input voltages ( $V_{AIN}$ ) above the analog reference<sup>1)</sup> ( $V_{AREF}$ ) on selected input pins (GxORCy) and generates a service request trigger (GxORCOUTy).

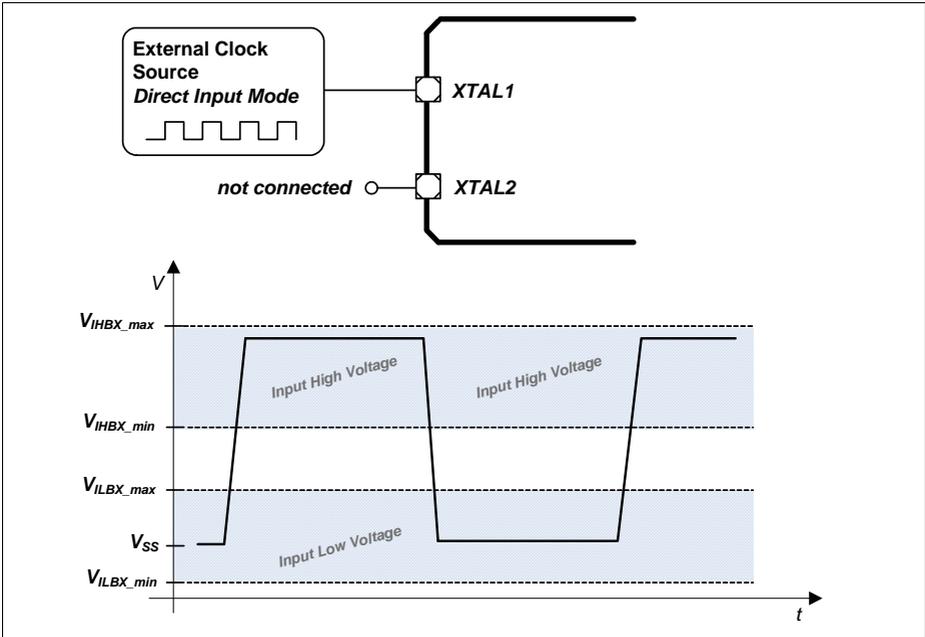
*Note: These parameters are not subject to production test, but verified by design and/or characterization.*

The parameters in **Table 28** apply for the maximum reference voltage  $V_{AREF} = V_{DDA} + 50 \text{ mV}$ .

**Table 28 ORC Parameters** (Operating Conditions apply)

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
DC Switching Level	$V_{ODC}$	CC	100	125	200	mV	$V_{AIN} \geq V_{AREF} + V_{ODC}$
Hysteresis	$V_{OHYS}$	CC	50	–	$V_{ODC}$	mV	
Detection Delay of a persistent Overvoltage	$t_{ODD}$	CC	55	–	450	ns	$V_{AIN} \geq V_{AREF} + 200 \text{ mV}$
			45	–	105	ns	$V_{AIN} \geq V_{AREF} + 400 \text{ mV}$
Always detected Overvoltage Pulse	$t_{OPDD}$	CC	440	–	–	ns	$V_{AIN} \geq V_{AREF} + 200 \text{ mV}$
			90	–	–	ns	$V_{AIN} \geq V_{AREF} + 400 \text{ mV}$
Never detected Overvoltage Pulse	$t_{OPDN}$	CC	–	–	49	ns	$V_{AIN} \geq V_{AREF} + 200 \text{ mV}$
			–	–	30	ns	$V_{AIN} \geq V_{AREF} + 400 \text{ mV}$
Release Delay	$t_{ORD}$	CC	65	–	105	ns	$V_{AIN} \leq V_{AREF}$
Enable Delay	$t_{OED}$	CC	–	100	200	ns	

1) Always the standard VADC reference, alternate references do not apply to the ORC.



**Figure 22 Oscillator in Direct Input Mode**

**Table 41 Flash Memory Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Data Retention Time, User Configuration Block (UCB) <sup>3)4)</sup>	$t_{RTU}$ CC	20	–	–	years	Max. 4 erase/program cycles per UCB
Endurance on 64 Kbyte Physical Sector PS4	$N_{EPS4}$ CC	10000	–	–	cycles	BA-marking devices only! Cycling distributed over life time <sup>5)</sup>

- 1) In case the Program Verify feature detects weak bits, these bits will be programmed once more. The reprogramming takes an additional time of 5.5 ms.
- 2) The following formula applies to the wait state configuration:  $FCON.WSPFLASH \times (1 / f_{CPU}) \geq t_a$ .
- 3) Storage and inactive time included.
- 4) Values given are valid for an average weighted junction temperature of  $T_j = 110^\circ\text{C}$ .
- 5) Only valid with robust EEPROM emulation algorithm, equally cycling the logical sectors. For more details see the Reference Manual.

### 3.3.4 Phase Locked Loop (PLL) Characteristics

#### Main and USB PLL

**Table 44 PLL Parameters**

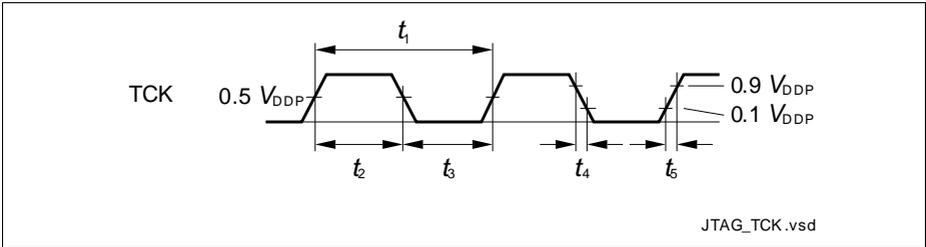
Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Accumulated Jitter	$D_P$ CC	–	–	±5	ns	accumulated over 300 cycles $f_{SYS} = 120$ MHz
Duty Cycle <sup>1)</sup>	$D_{DC}$ CC	46	50	54	%	Low pulse to total period, assuming an ideal input clock source
PLL base frequency	$f_{PLLBASE}$ CC	30	–	140	MHz	
VCO input frequency	$f_{REF}$ CC	4	–	16	MHz	
VCO frequency range	$f_{VCO}$ CC	260	–	520	MHz	
PLL lock-in time	$t_L$ CC	–	–	400	µs	

1) 50% for even K2 divider values,  $50 \pm (10/K2)$  for odd K2 divider values.

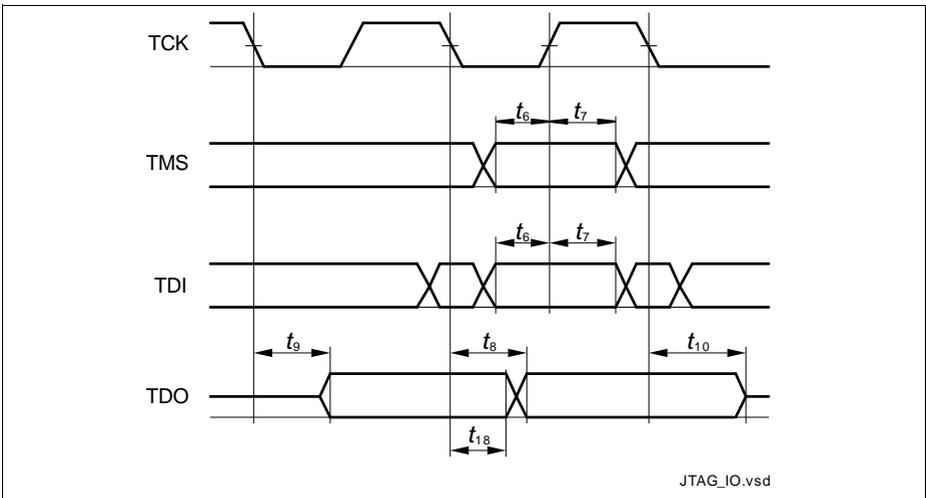
**Slow Internal Clock Source**

**Table 46 Slow Internal Clock Parameters**

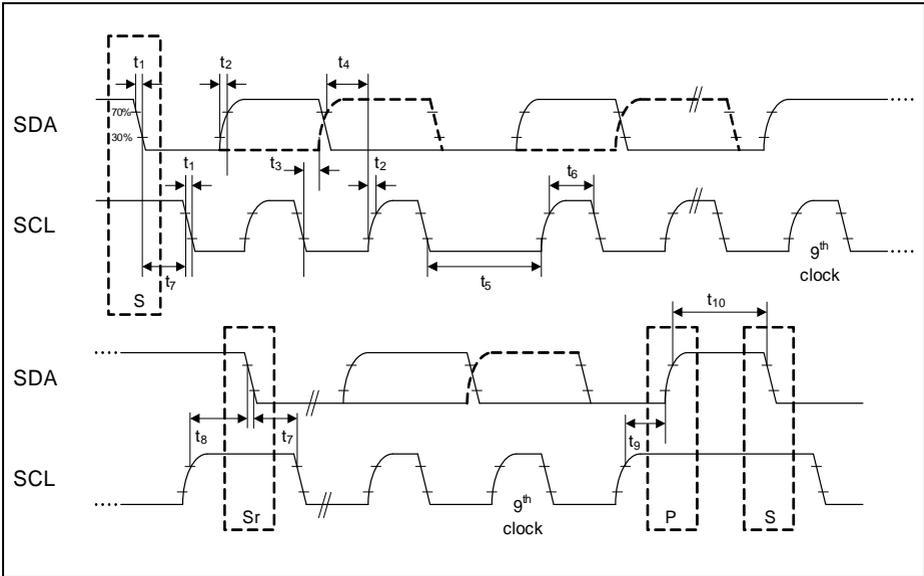
Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Nominal frequency	$f_{OSI}$ CC	–	32.768	–	kHz	
Accuracy	$\Delta f_{OSI}$ CC	-4	–	4	%	$V_{BAT} = \text{const.}$ $0\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$
		-5	–	5	%	$V_{BAT} = \text{const.}$ $T_A < 0\text{ }^{\circ}\text{C}$ or $T_A > 85\text{ }^{\circ}\text{C}$
		-5	–	5	%	$2.4\text{ V} \leq V_{BAT}$ , $T_A = 25\text{ }^{\circ}\text{C}$
		-10	–	10	%	$1.95\text{ V} \leq V_{BAT} < 2.4\text{ V}$ , $T_A = 25\text{ }^{\circ}\text{C}$
Start-up time	$t_{OSIS}$ CC	–	50	–	$\mu\text{s}$	



**Figure 28 Test Clock Timing (TCK)**



**Figure 29 JTAG Timing**



**Figure 35 USIC IIC Stand and Fast Mode Timing**

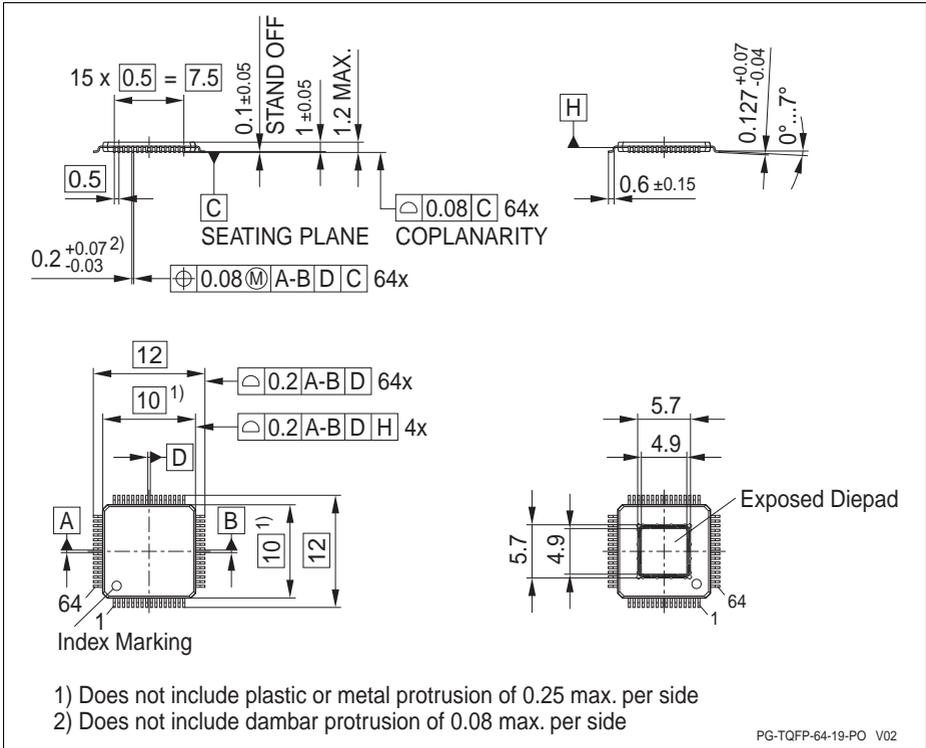
### 3.3.9.4 Inter-IC Sound (IIS) Interface Timing

The following parameters are applicable for a USIC channel operated in IIS mode.

*Note: Operating Conditions apply.*

**Table 55 USIC IIS Master Transmitter Timing**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clock period	$t_1$ CC	33.3	–	–	ns	
Clock HIGH	$t_2$ CC	0.35 x $t_{1min}$	–	–	ns	
Clock Low	$t_3$ CC	0.35 x $t_{1min}$	–	–	ns	
Hold time	$t_4$ CC	0	–	–	ns	
Clock rise time	$t_5$ CC	–	–	0.15 x $t_{1min}$	ns	



**Figure 45 PG-TQFP-64-19 (Plastic Green Low Profile Quad Flat Package)**

All dimensions in mm.

You can find complete information about Infineon packages, packing and marking in our Infineon Internet Page "Packages": <http://www.infineon.com/packages>